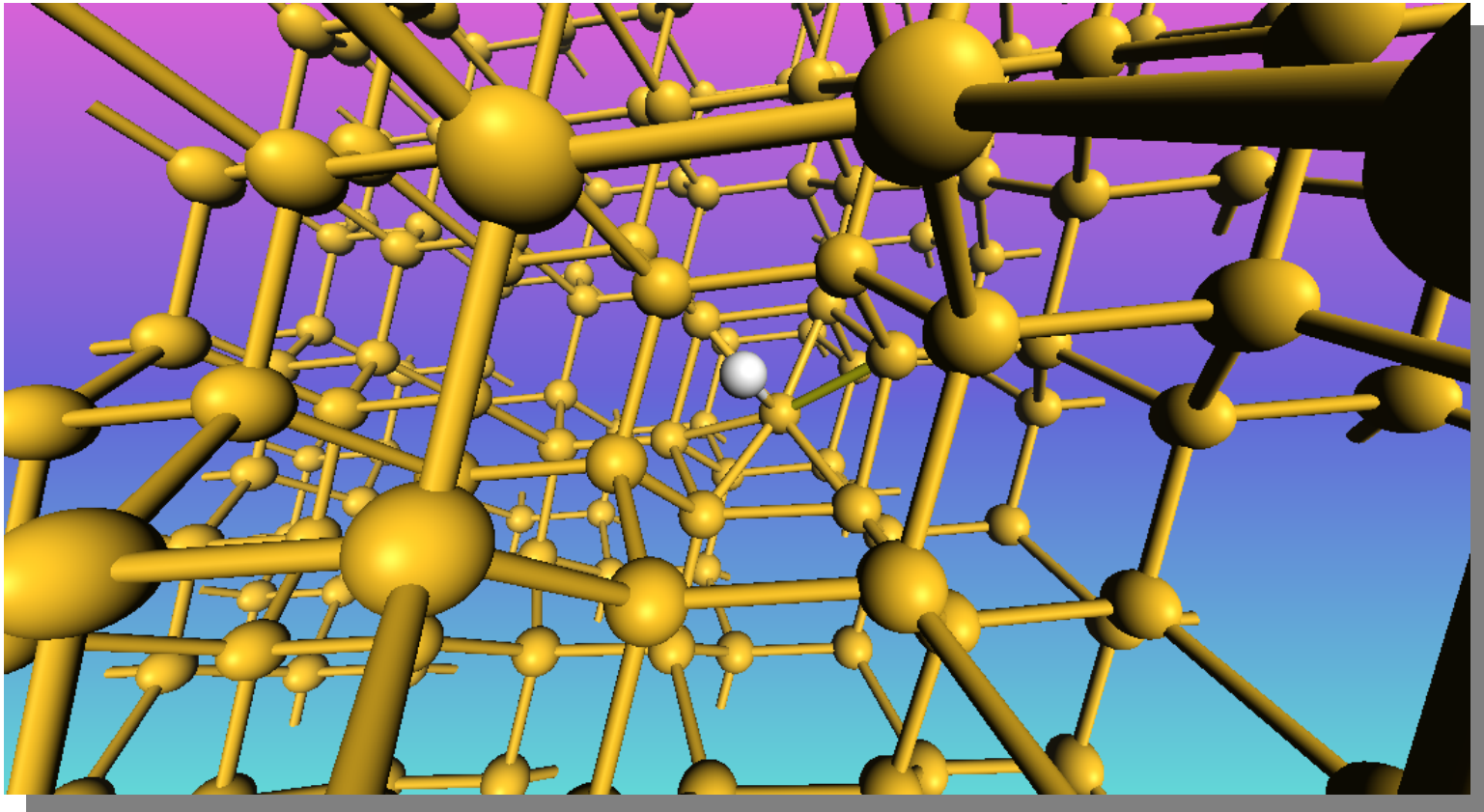


Defects in semiconductors using random structure searching

Andrew Morris



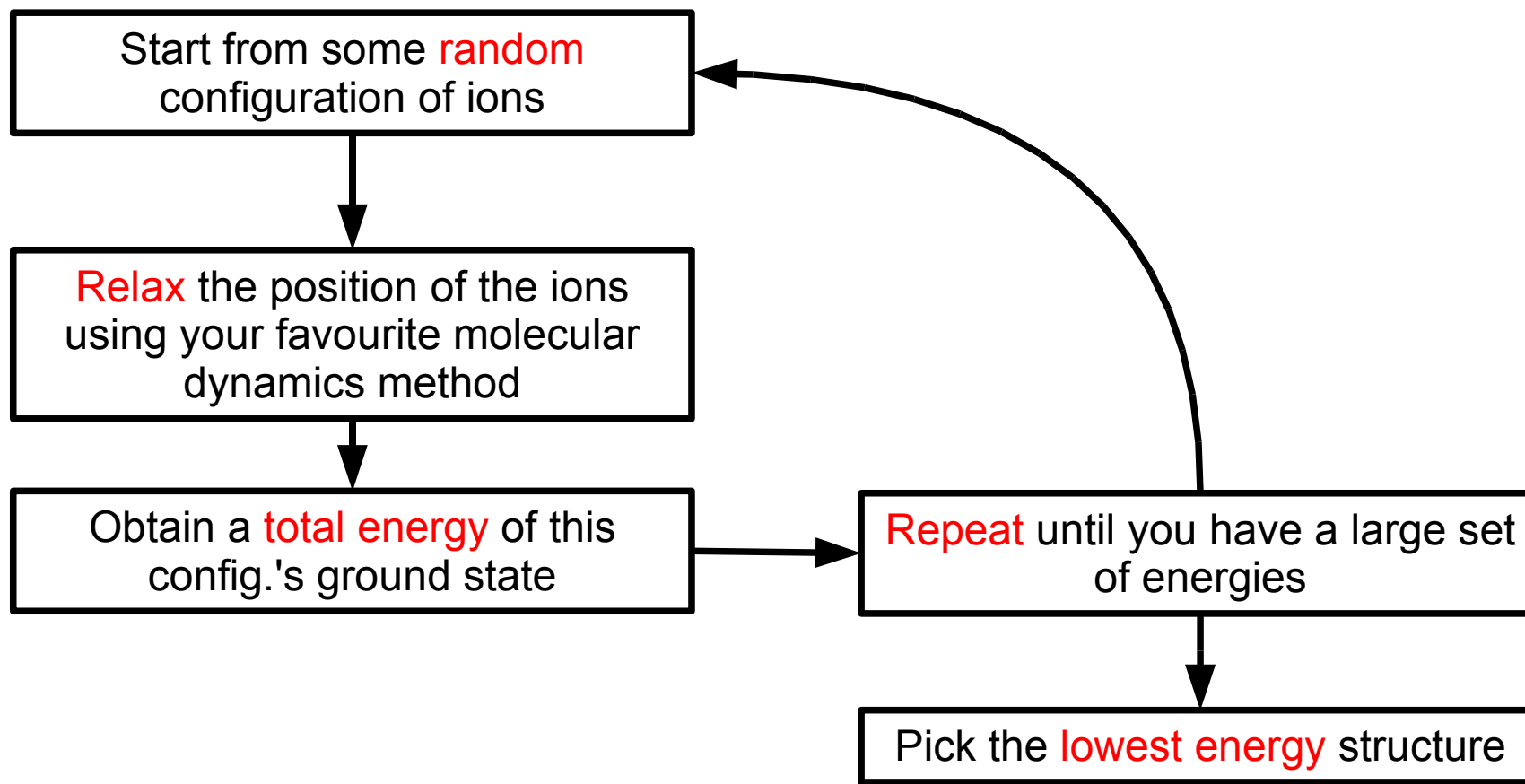
*Theory of Condensed Matter
Cavendish Laboratory
University of Cambridge*



- **What** are Random Structure Searches?
- How do we **apply** them to defect problems?
- Fishing, Polishing and Embedding
- Digression into **Multi-B Special K-point** sampling
- Silicon Self-Interstitials - *A Test of the Method*
- Silicon and Hydrogen Interstitials - *A Demonstration of the Method finding new things*
- Relative stabilities – what **actually** forms?
- Conclusions



- Probably the most **simple** way to find the lowest energy structure of a solid



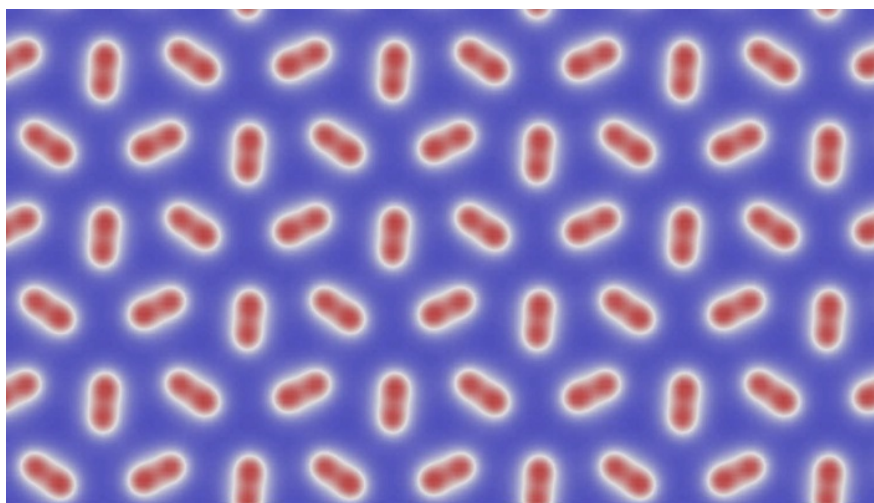


When is H₂O not water? CJP + RJN

JCP 2007

Aluminium Hydride. CJP + RJN

PRB 2007



Structure of phase III hydrogen. CJP + RJN
Nature Physics 2007

Graphite interlocation compounds GC + CJP + BDS + RJN

PRB 2007

High Pressure Silane CJP + RJN

PRL 2006



- Test calculations

- *High Pressure Silane CJP + RJN*

PRL 2006

- How do we **modify** the existing method to get accurate results for semiconductors?

- Start with every possible config. of the system, we must get the **right** answer

Not Possible!

- How to create starting configs. that **constrain** the results?

- Make a **hole** in a perfect lattice ... more later

Method



- Fishing

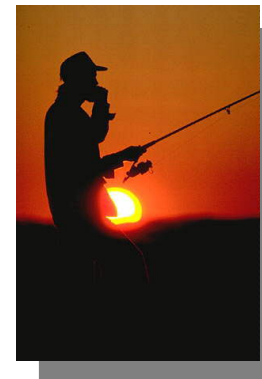


- Polishing



- Embedding





- Catch as many **fish** as you can.
 - Small cell 32-54 bulk atoms
 - 0.05eV/Å force tolerance
 - Darwin (Supercomputer)
- Don't catch any **red** herrings.
 - Still has to be accurate :
 - 2x2x2 **Multi-B** special k-point sampling (**More Later**)
 - Good pseudopotentials
 - DFT
 - High** planewave cutoff of basis set
- Know when you've caught **whopper**.
 - Calculate space group symmetries
 - Good recognition of when two structures are the **same**

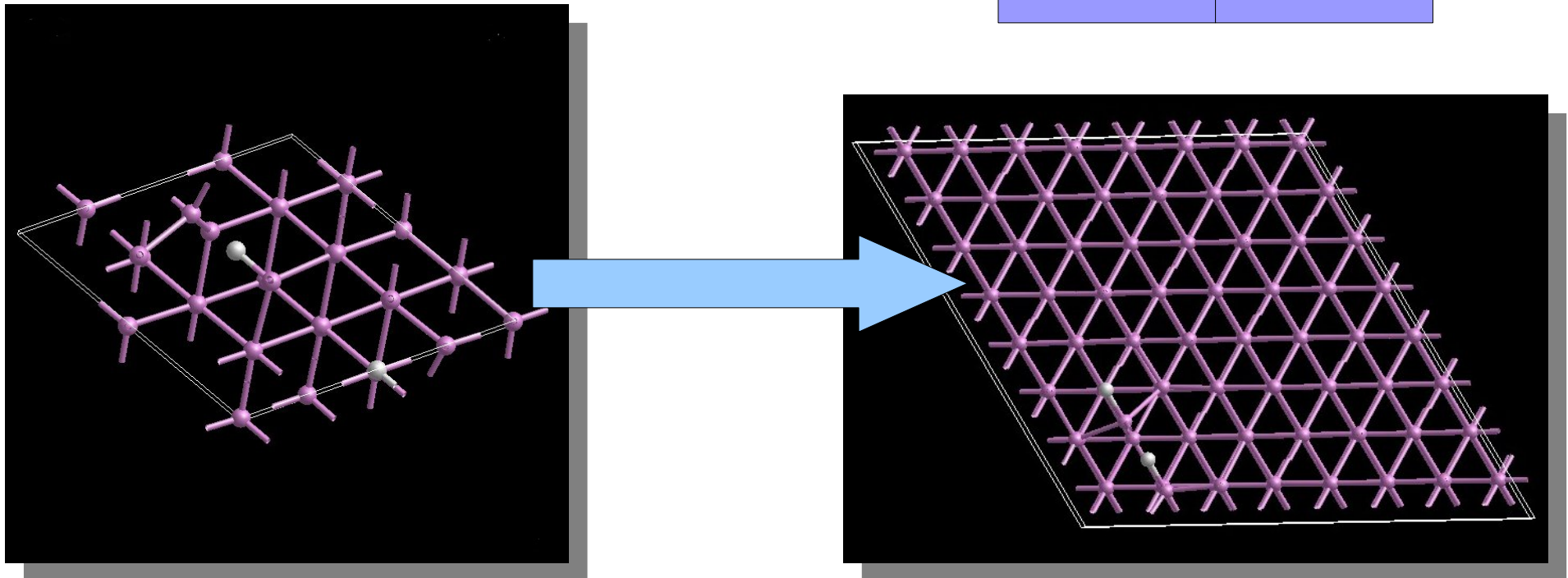
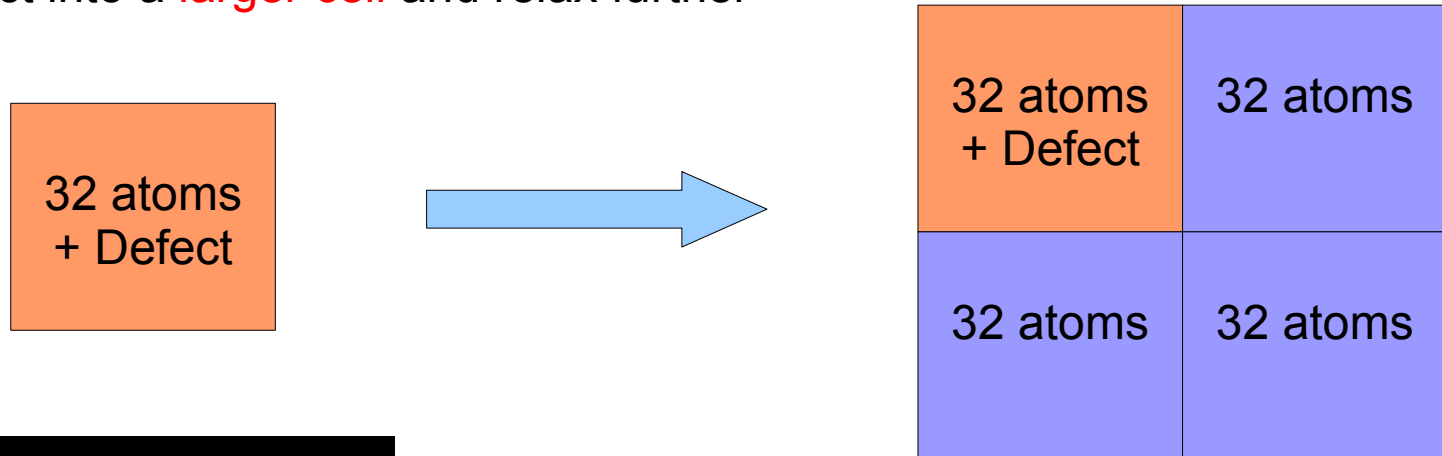


- Take:
 - The **lowest energy** structures
 - The **high symmetry** structures
 - Anything that looks interesting
- Do more DFT
 - High tolerance relaxation
 - OTF pseudopotentials
- Take *similutide.x86*
 - See what's well relaxed
 - See what structures are the same
 - Even** if they have different energies
 - Even** if they are of low symmetry



Embedding

- A 32 atom cell is not **large** enough for an accurate total energy calculation. So we need to put the defect into a **larger cell** and relax further



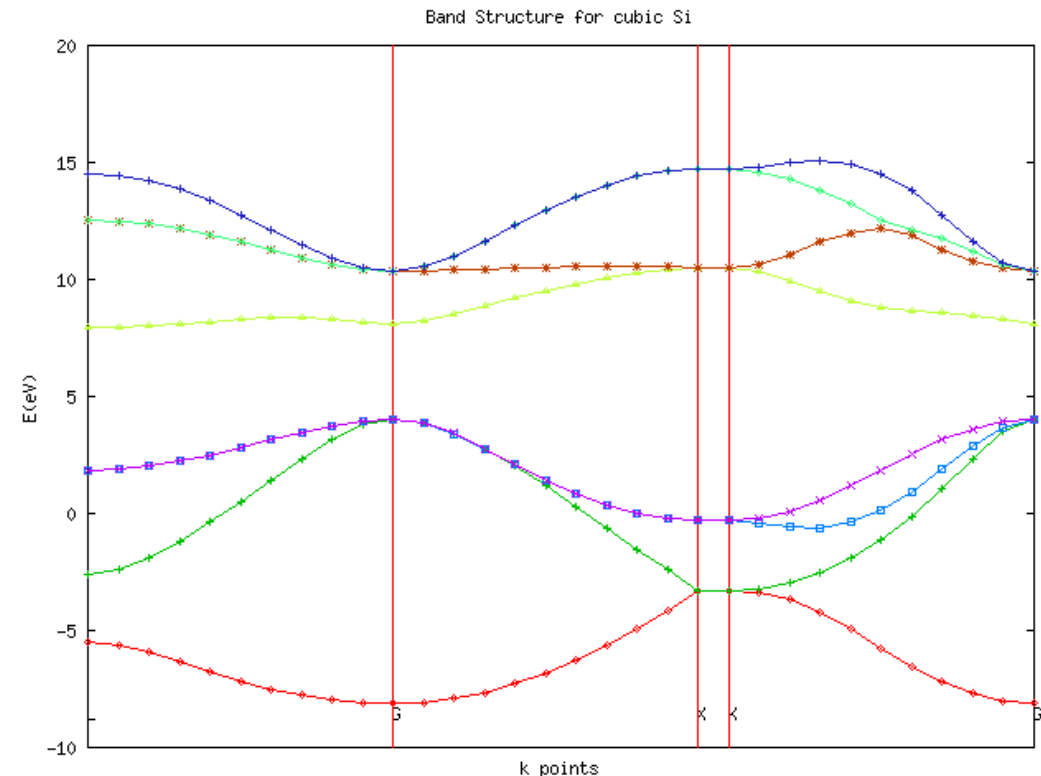
Electronic Structure Method
Search Method (Fishing / Polish / Embed)
K-point integration Method
Constraint Method

Special K-point Sampling



- In CASTEP we use plane-waves as a **basis set** for the electron's wavefunction. These are easy to represent in reciprocal space as k -points.
- In order to get the **total energy** of a crystal we must **sum** over all k , *i.e.* k in the first BZ. But k is **continuous** – so we need a way to **approximate** the integral.

D.J. Chadi and M.L. Cohen, *Tight Binding Calculations of the Valence Bands of Diamond and Zincblende Crystals*. Phys. Stat. Sol. (b) **68**, 405 (1975).





If $E(k)$ is some 1-D function, real and symmetric about 0, (the Γ point), we can express this as the following **Fourier series**:

$$E(k) = b_0 + b_1 \cos\left(\frac{2\pi k}{G}\right) + \dots$$

If $E(k)$ is constant then the answer is b_0 **any** k will give the correct value. If not, we need to **sample** such that only the b_0 remains in the Fourier series, as all higher terms should integrate to 0.

Sample at **$k=0$** :

$$E(k) = b_0 + b_1 \cos\left(\frac{2\pi 0}{G}\right) + \dots = b_0 + b_1$$

Sample at **$k=G/4$** :

$$E(k) = b_0 + b_1 \cos\left(\frac{2\pi}{G} \frac{G}{4}\right) + \dots = b_0$$

So **different** k -points give different answers!



There is some point in the 1st BZ that gives the **best** approximation to an integral over all the BZ.

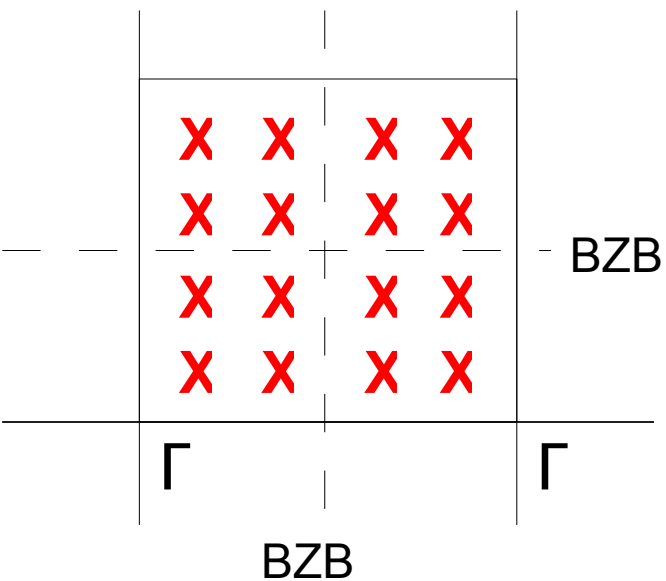
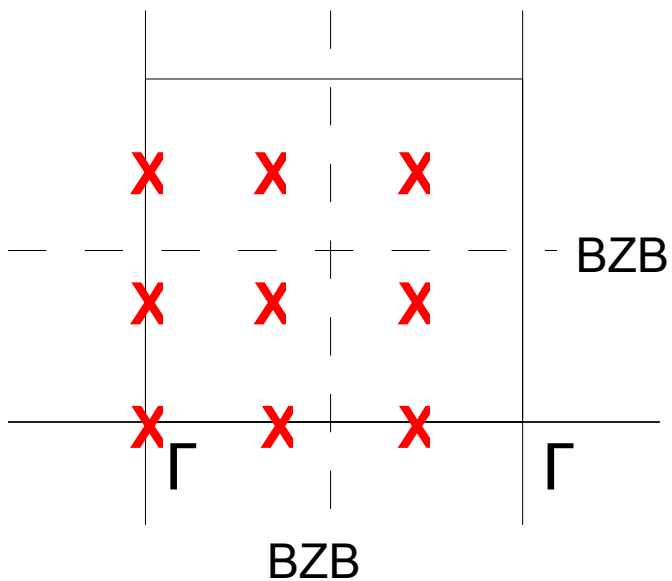
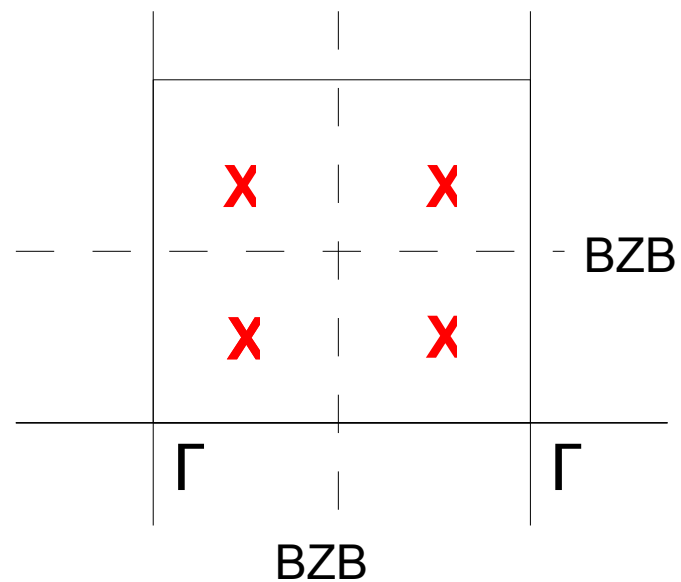
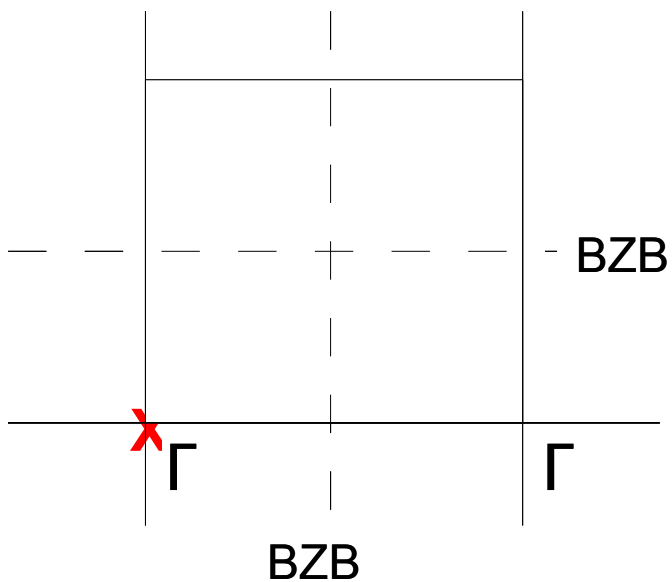
This is in terms of the **first-failure star** - the first G vector that gives rise to an error in the integration.

Further to this, Baldereschi **minimises** the error in the first-failure star.

In the old days, when you could only afford **one** k-point, the Baldereschi was the **best**.



If you have more than one k-point, where do you put them to get the best answer?

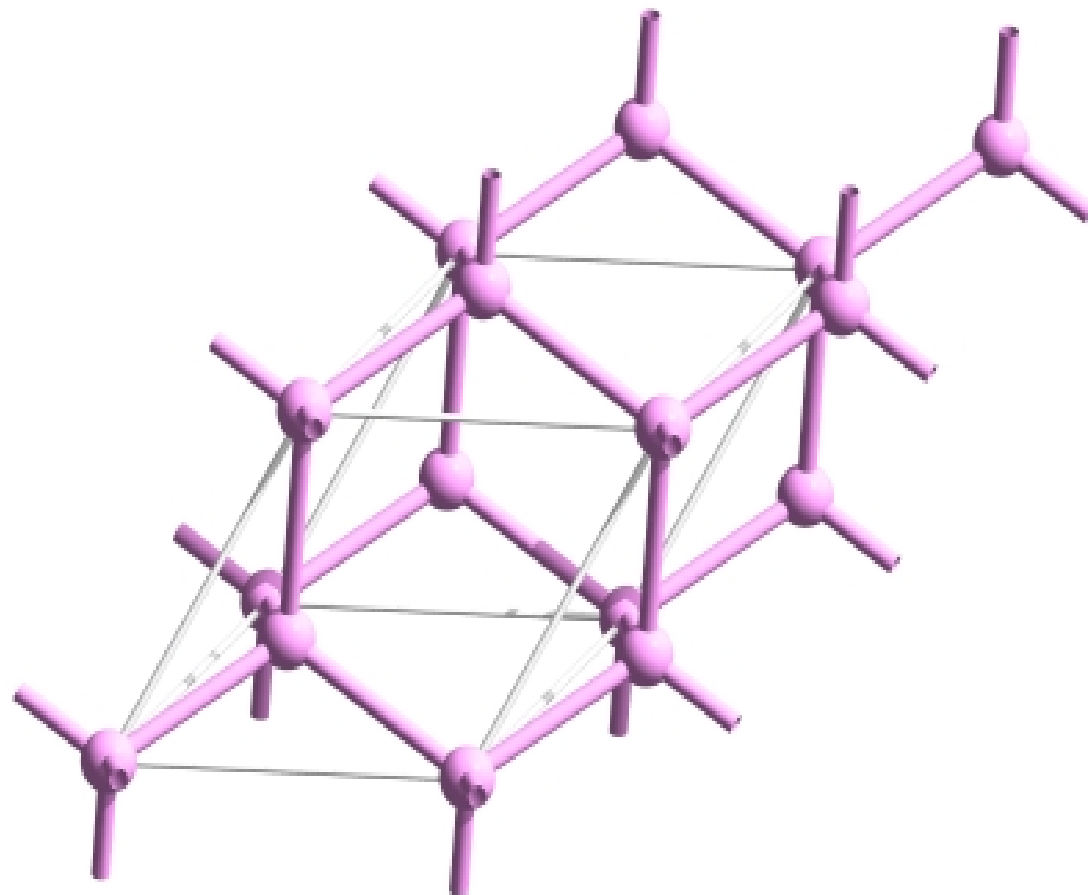


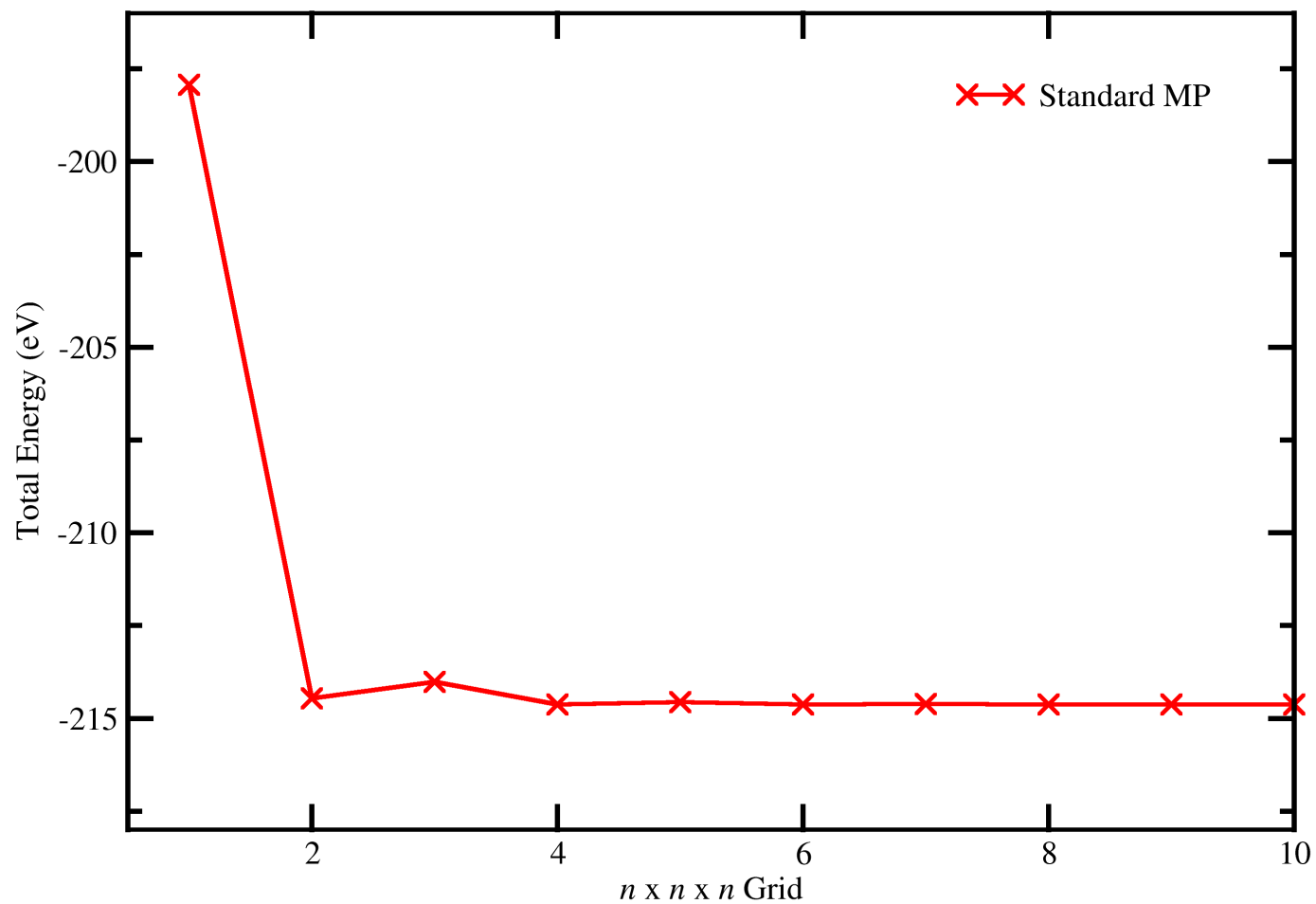


Our example system is **Silicon** with 2 atoms in the unit cell.

This cell is FCC.

We increase the standard MP grid in CASTEP from 1x1x1 to 10x10x10

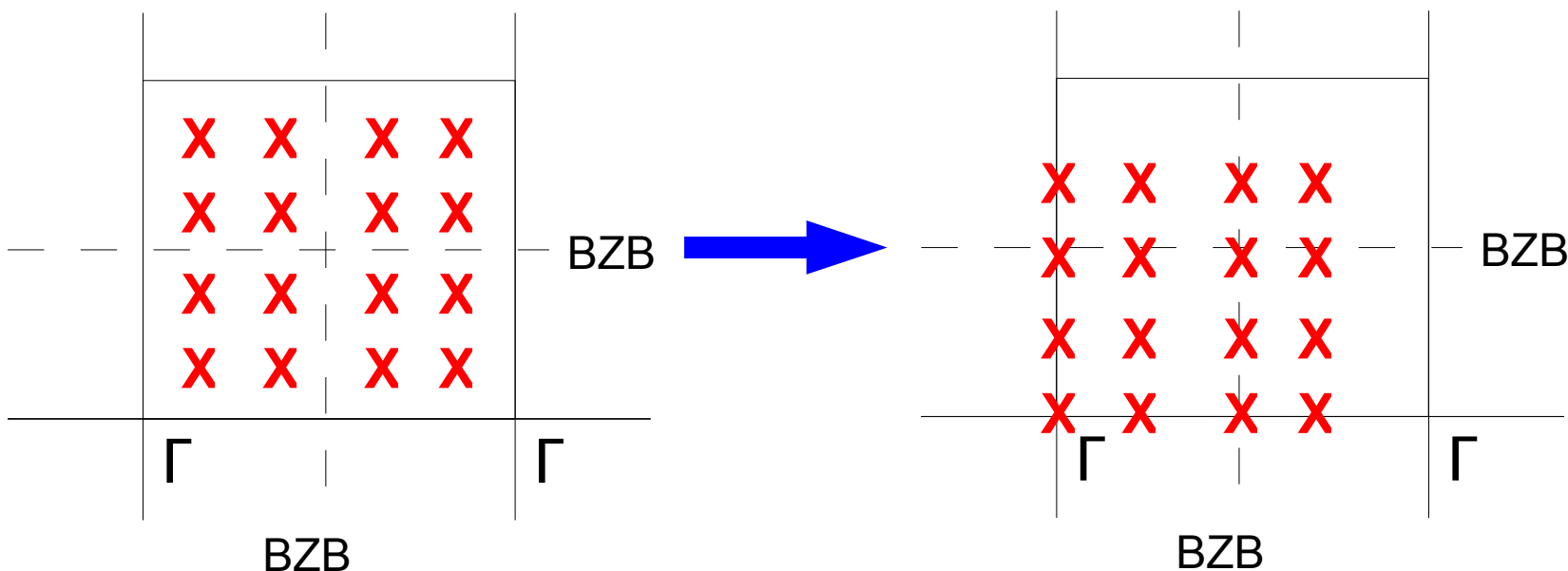




How can we improve?

The wiggleness of the line is due to some grids being **centred** on Γ and some not.

We could force all of the grids to have a point at Γ . (i.e. **shift** all the even grids)

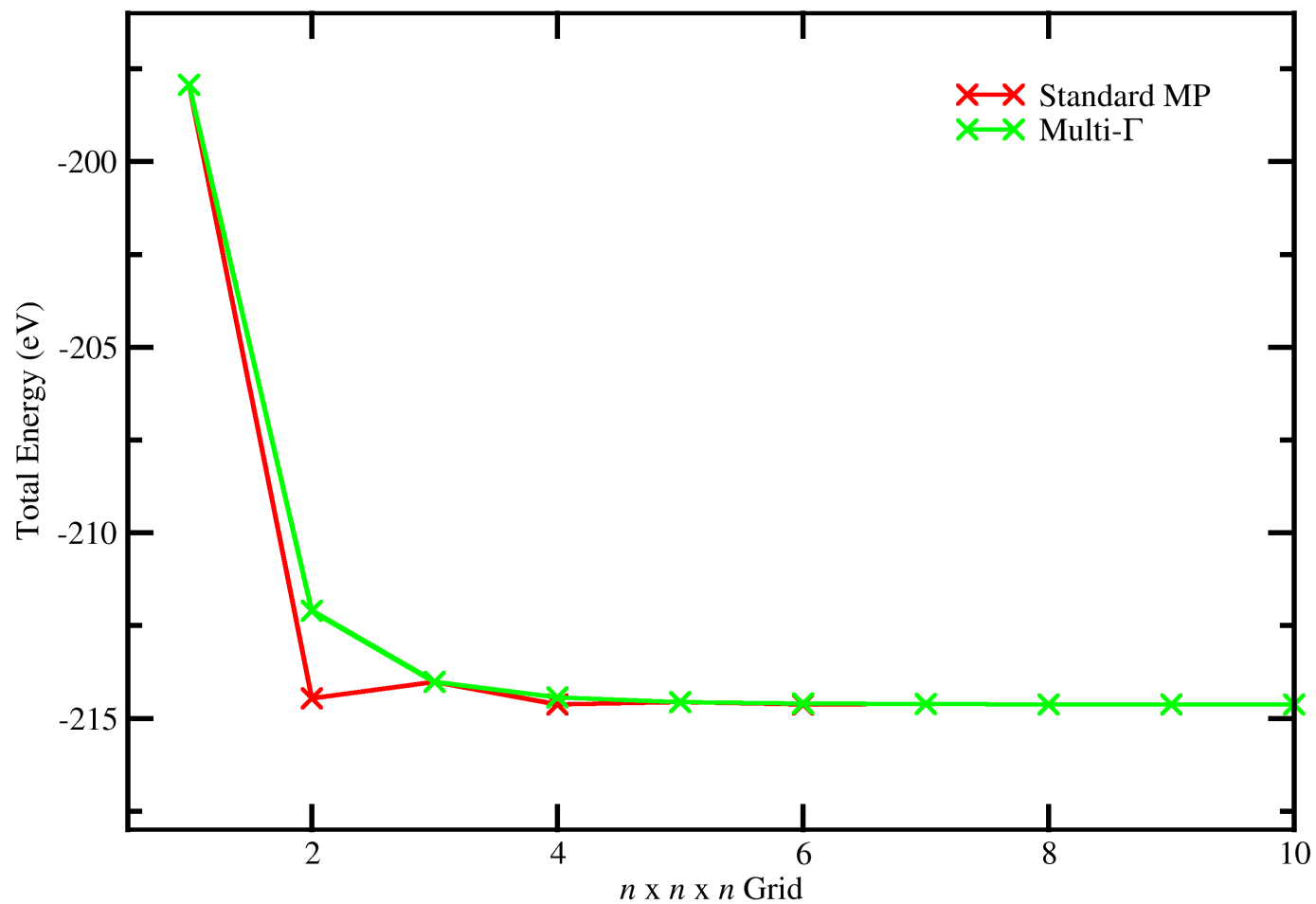


It might not be as good – as it has a point at Γ .

Will probably **break** the symmetry generation -

- my geom. opt. cells **don't** have symmetry anyway.

But at least it would be **systematic**.

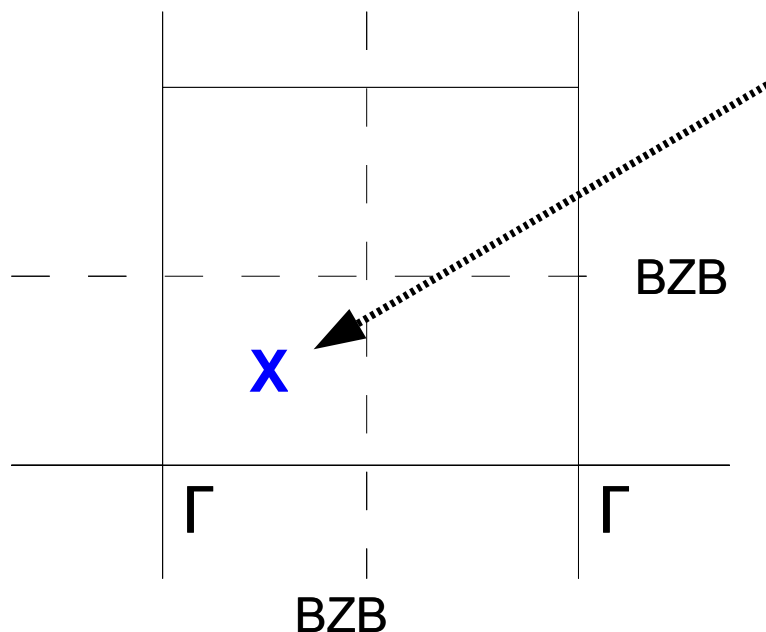




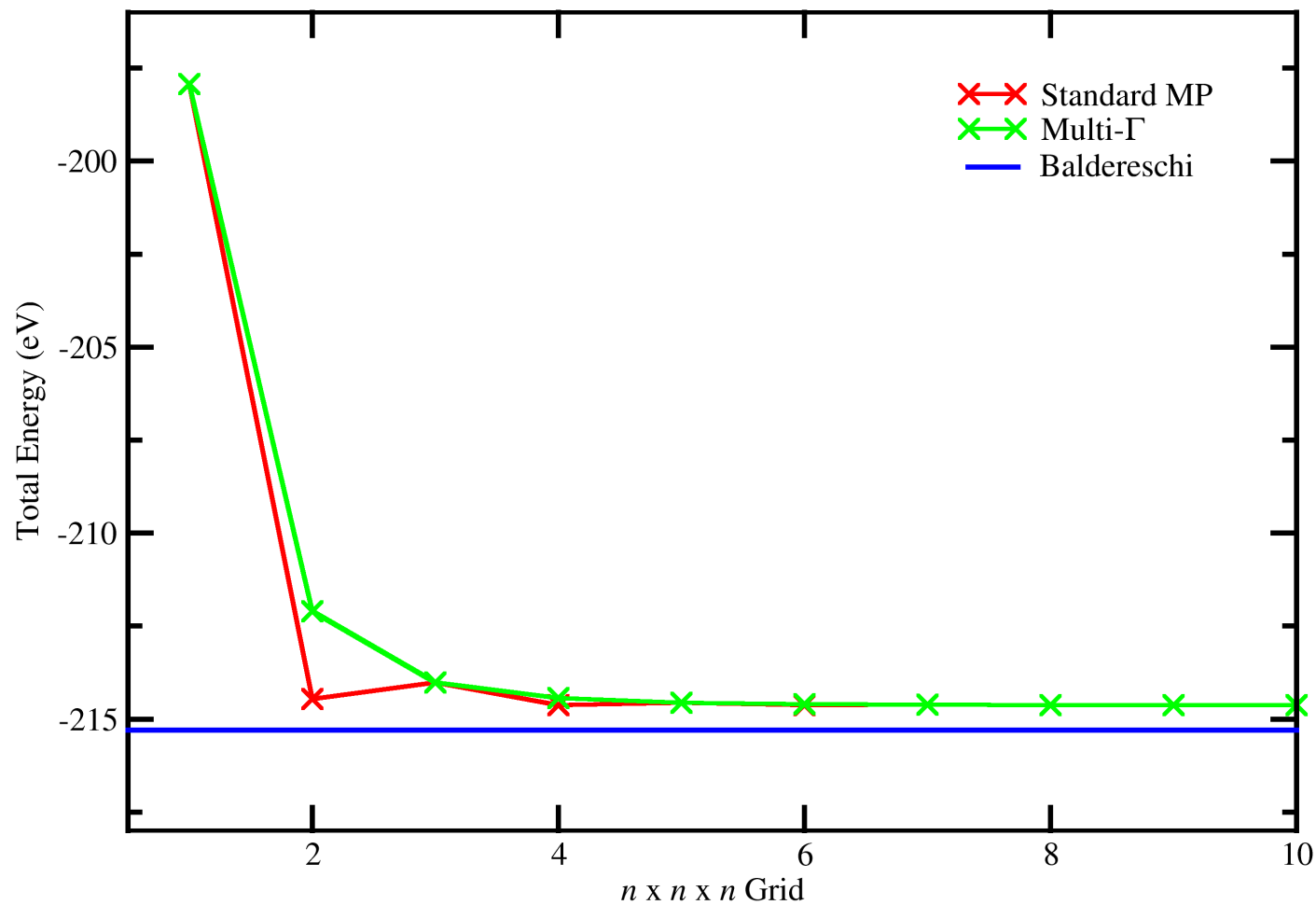
So we know now we must keep the grids **centred** on one point if we want smooth convergence.

So how does the Baldereschi point do?

1 x 1 x 1 grid (*i.e.* 1-kpoint)



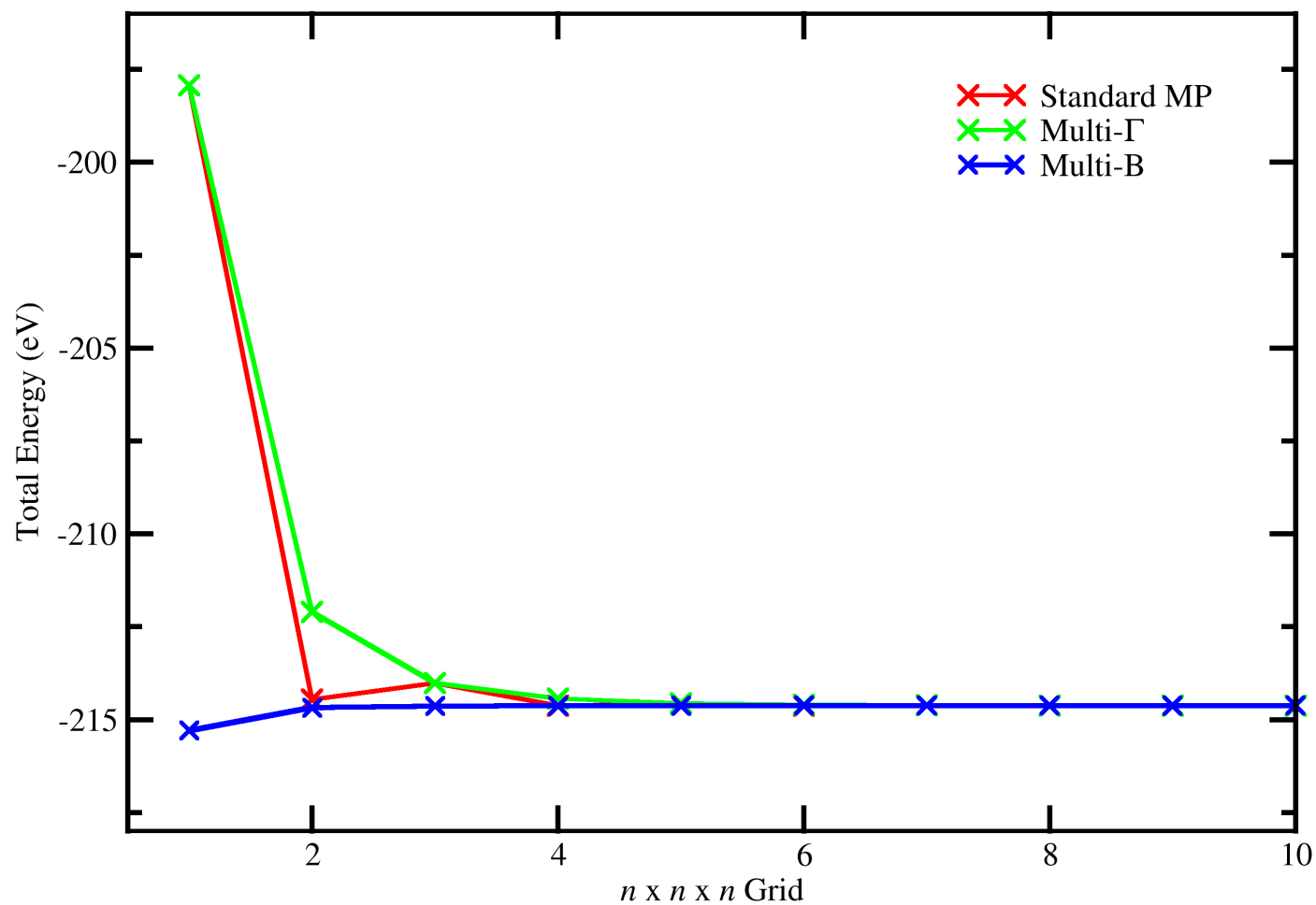
Baldereschi of SC cell (1/4, 1/4, 1/4)

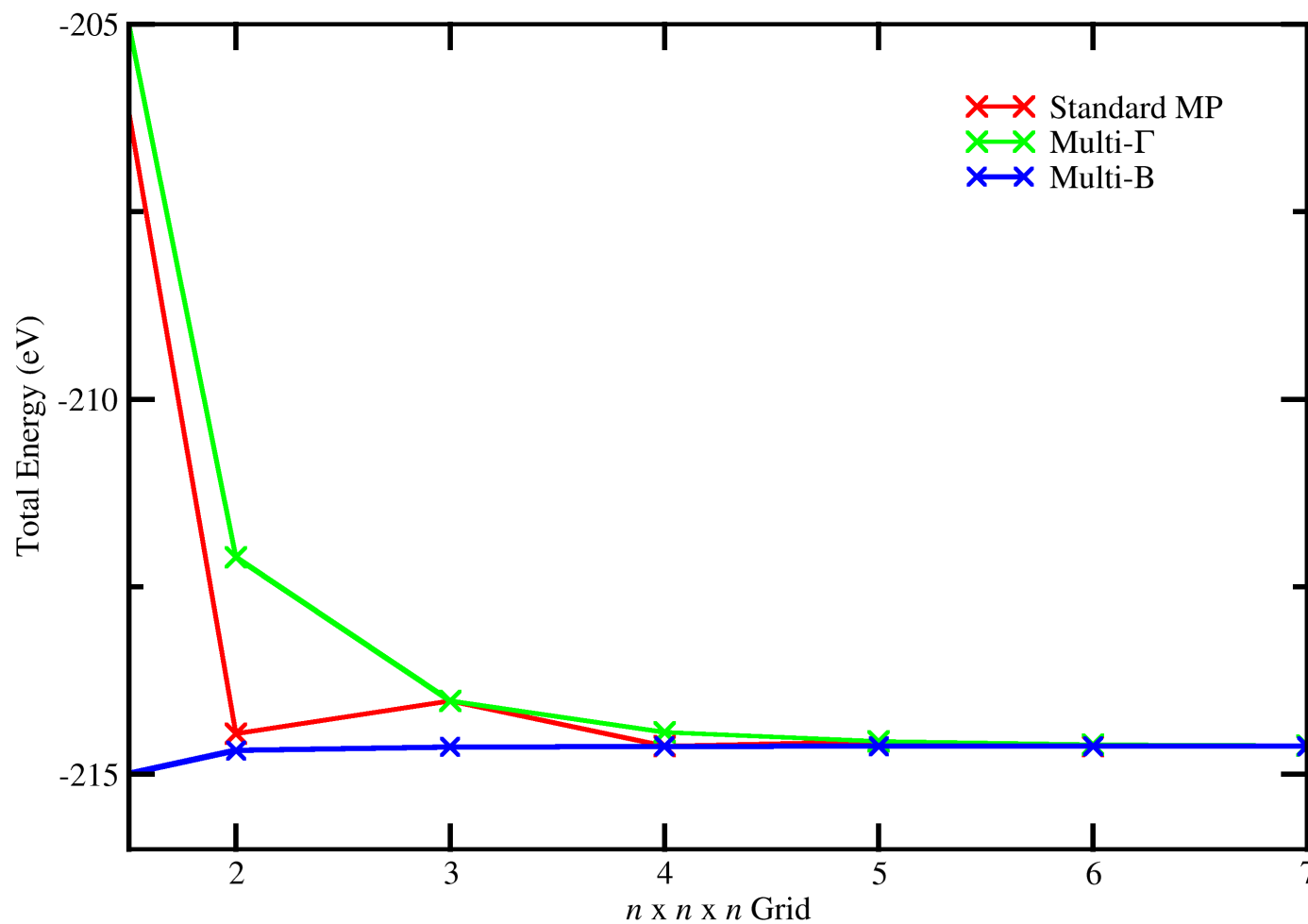


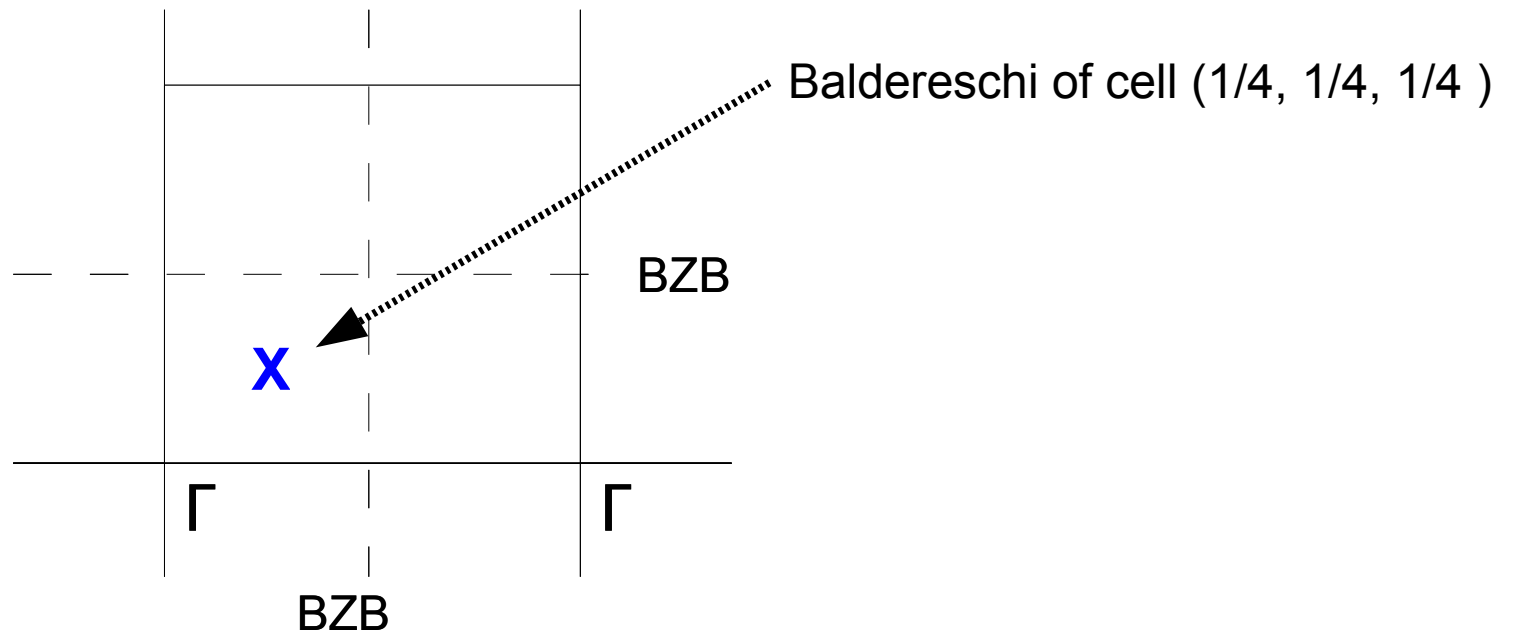
Can we do any better?



Baldereschi and Monkhorst and Pack?

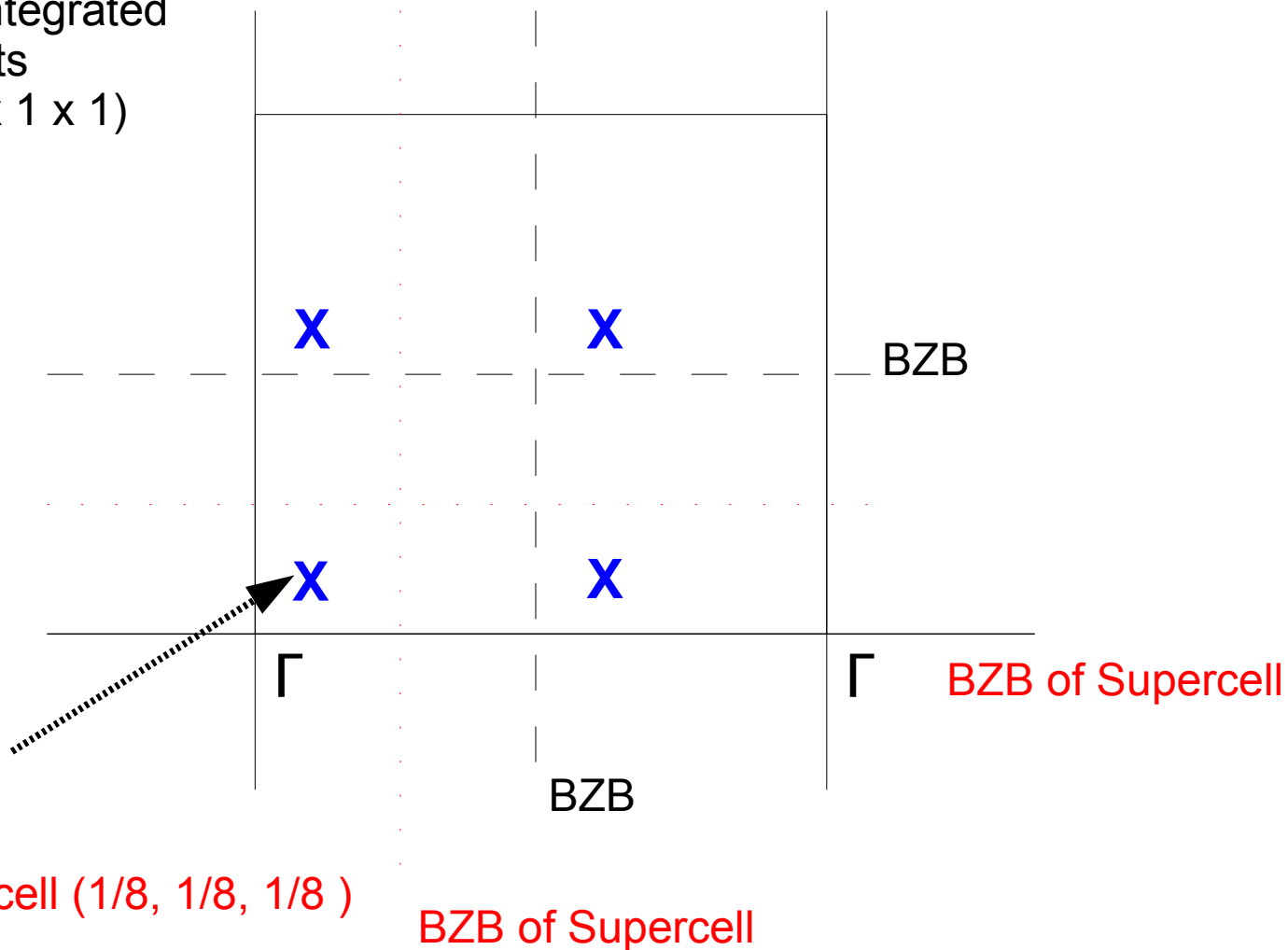








We have effectively integrated
the Silicon 16 cell at its
Baldereschi point ($1 \times 1 \times 1$)



Normal MP $2 \times 2 \times 2$
grid, but centred on
Baldereschi of super cell ($1/8, 1/8, 1/8$)

BZB of Supercell



If you can have only one k-point. **Surely** the Baldereschi point is best.

If you have **symmetry** in your system, and need **lots** of k-points, you probably need standard MP using Symmetry to reduce the k-point set.

Use Baldereschi + MP to **economically** sample bigger super-cells. (Useful in QMC).

(The QMC project I have going is using this method)

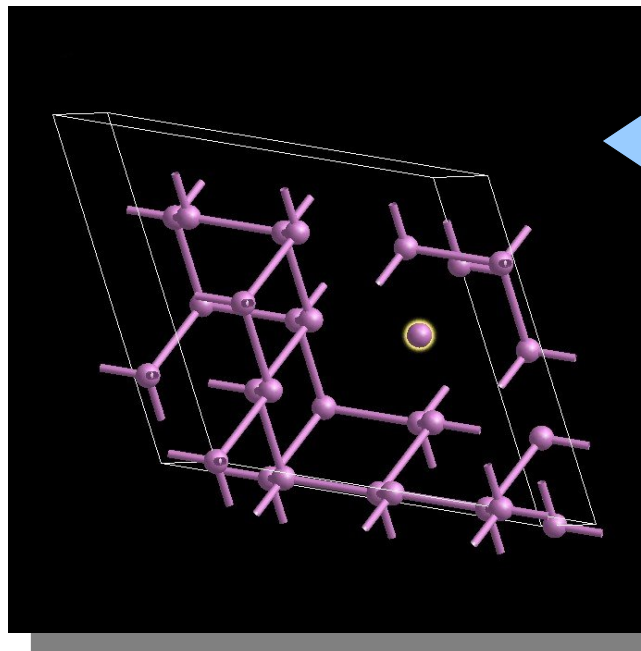
Electronic Structure Method
Search Method (Fishing / Polish / Embed)
K-point integration Method
Constraint Method

Silicon with Silicon Interstitials

A Test

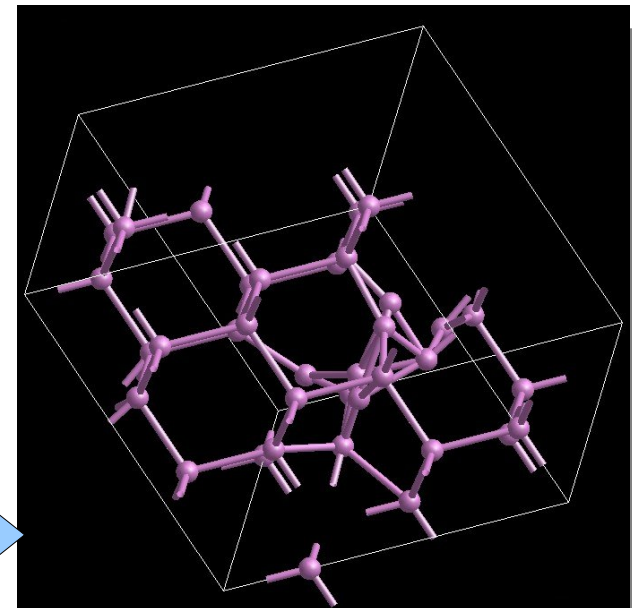


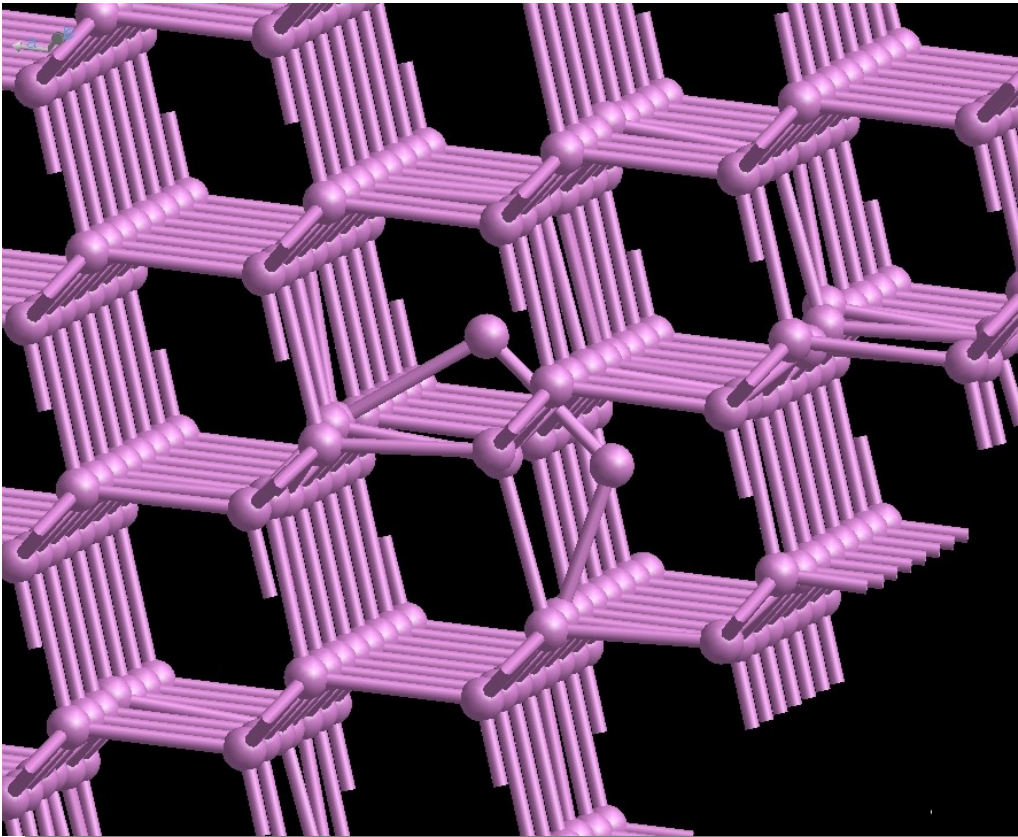
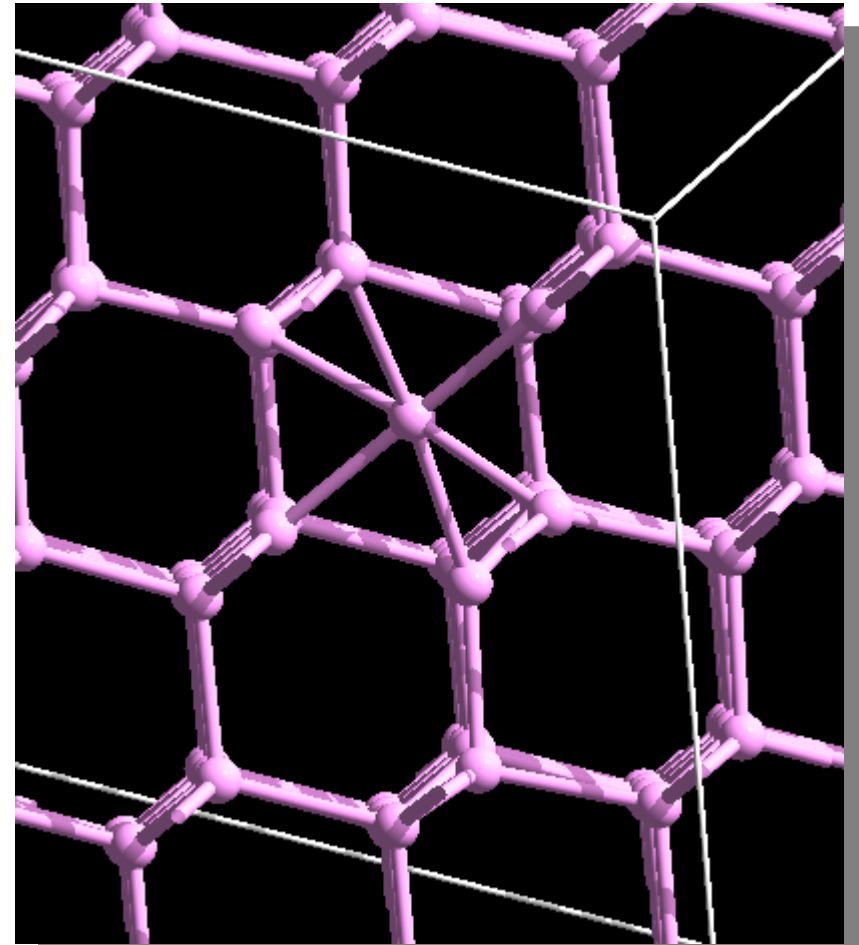
- Want to **constrain** the search.
- Do this by keeping the bulk intact and creating a **hole of randomness**.
- For example: Silicon self-interstitial
 - Bulk 54 atoms.
 - Remove 5 atoms from the bulk
 - Fish



Hole

Initial positions
before
randomisation



Split $\langle 110 \rangle$ 

Hexagonal

- Find both ground state structures quite **easily**.

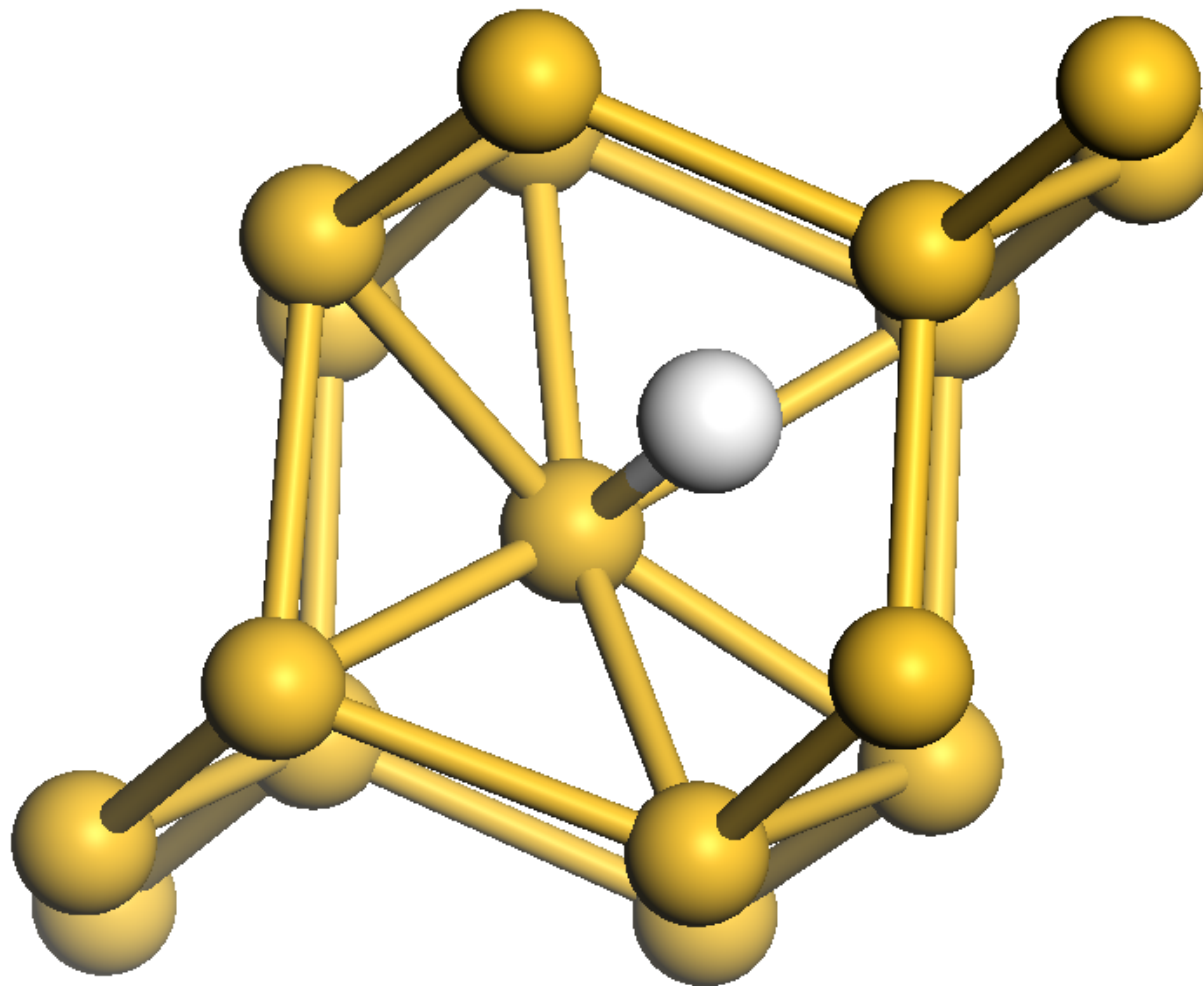
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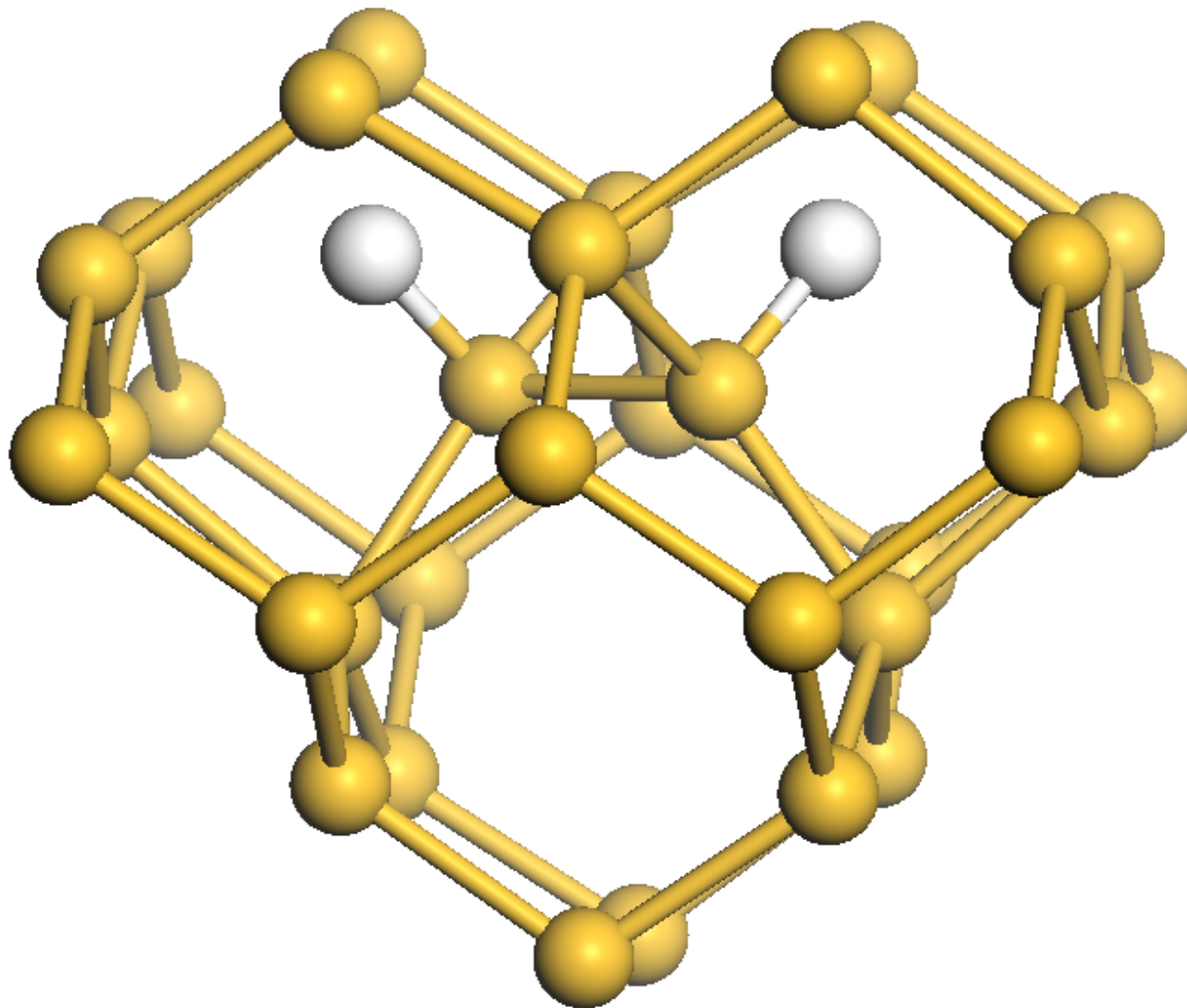
Ready!

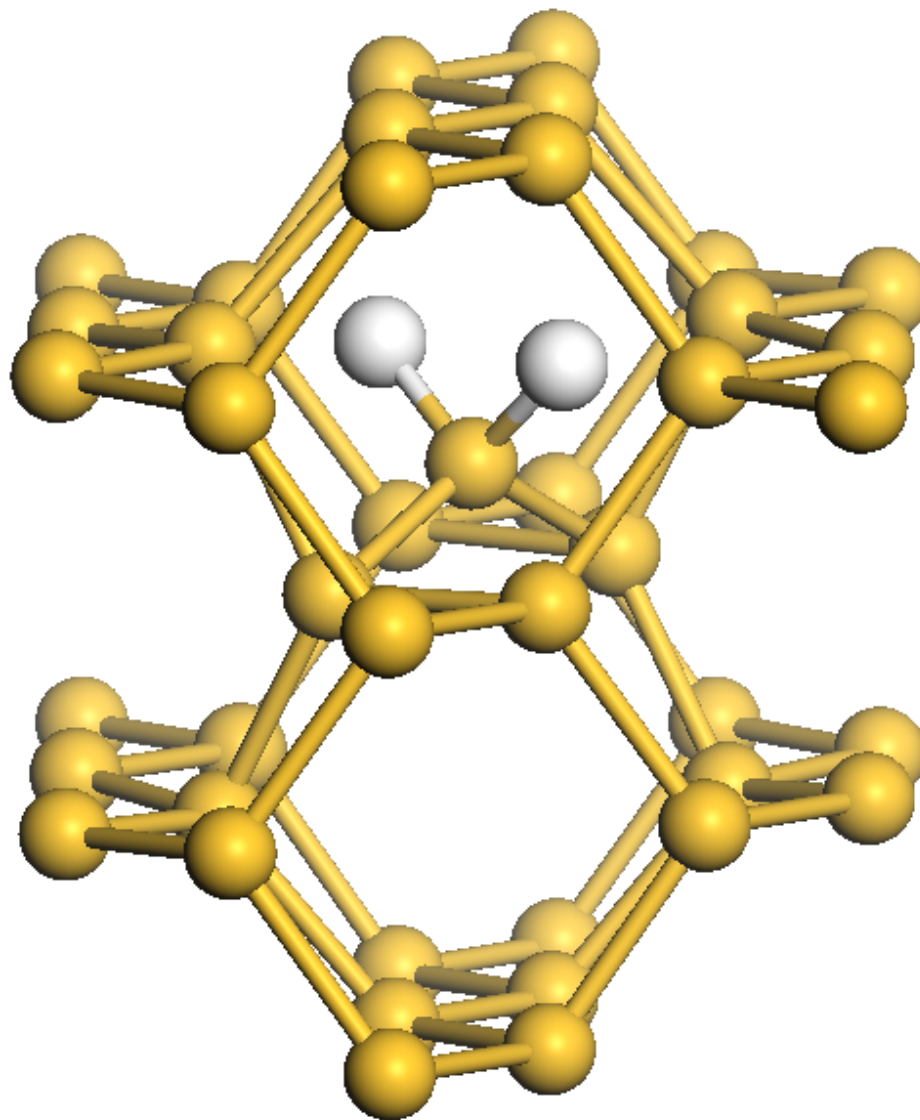
Silicon with Silicon and Hydrogen Interstitials

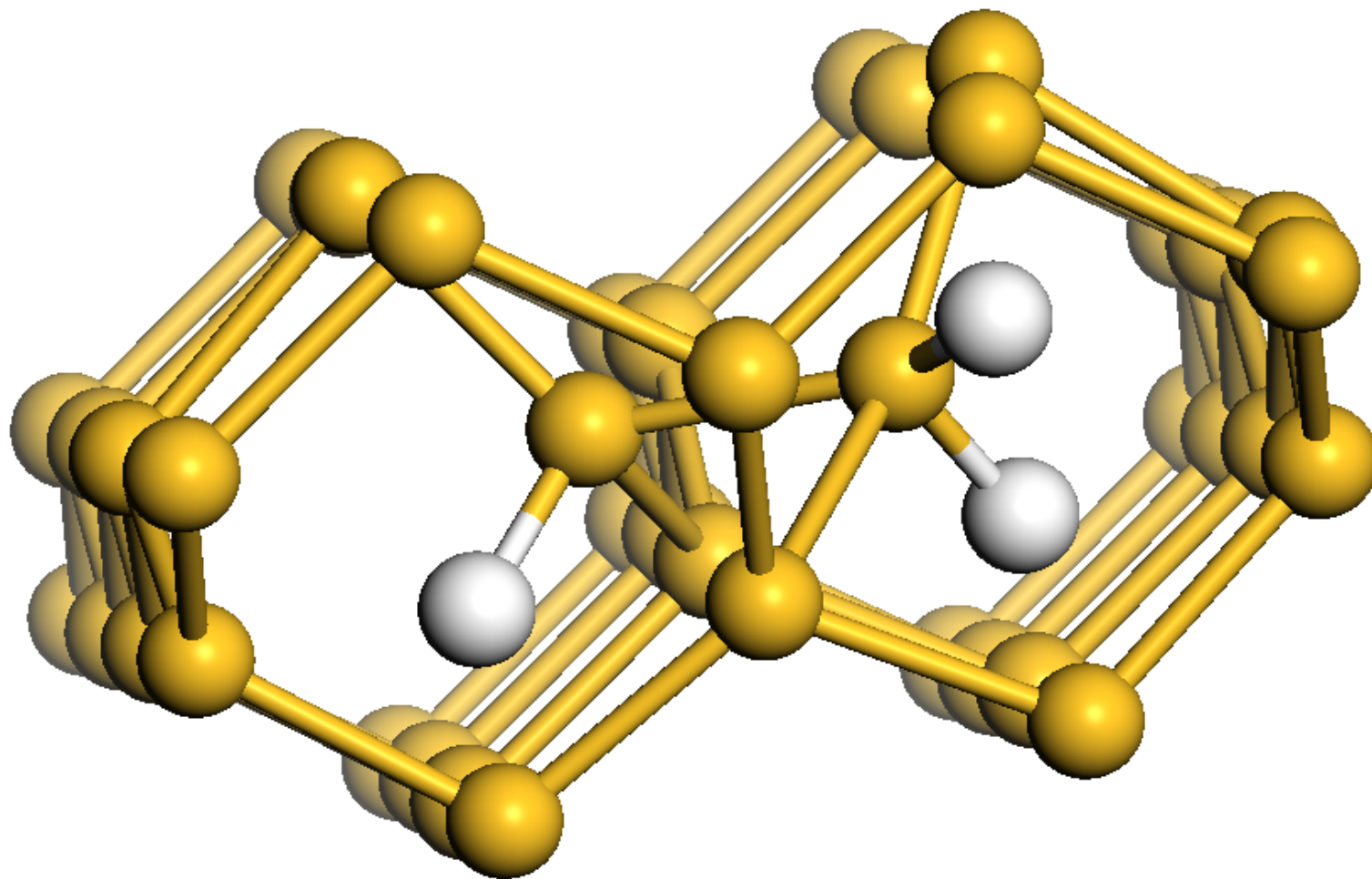


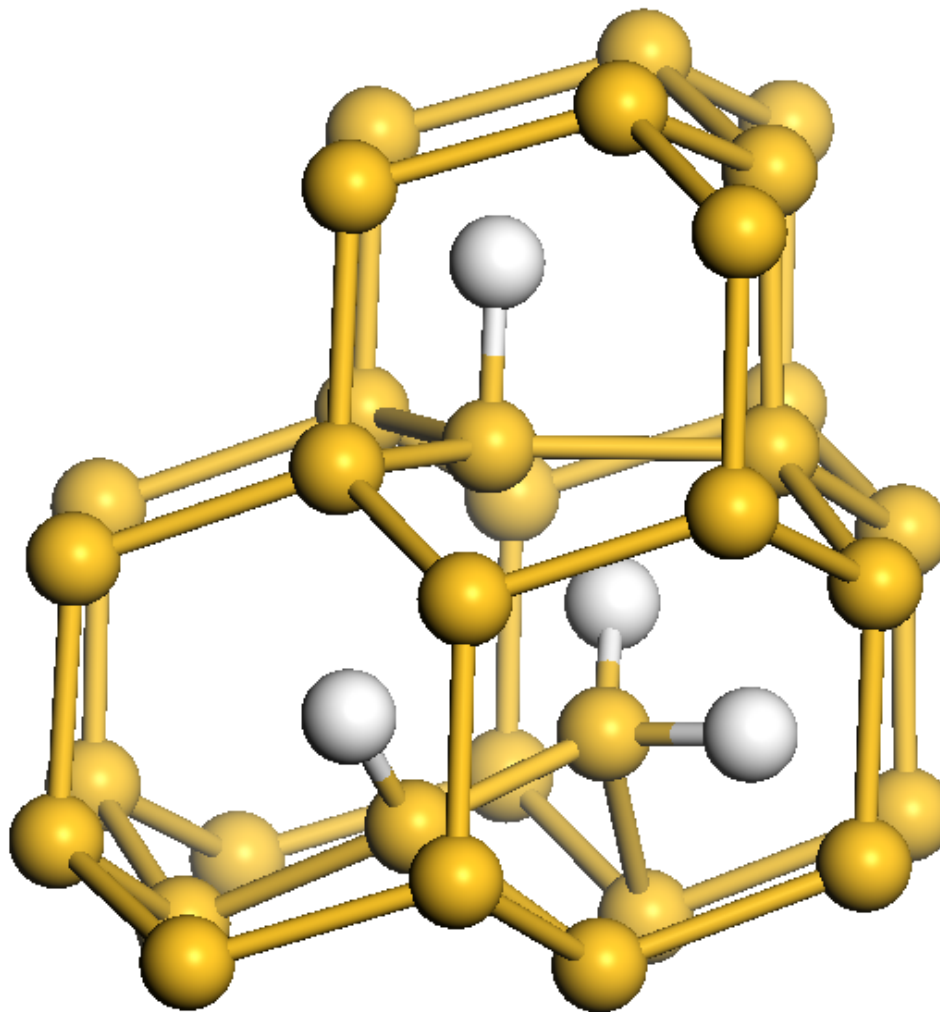
- Can use **small** cells
- Hydrogen changes energy states can get **activation** and **passivation** from H impurities
- Not fully understood. Only one defect so far found by experiment
- Some previous studies, carried out from symmetry arguments





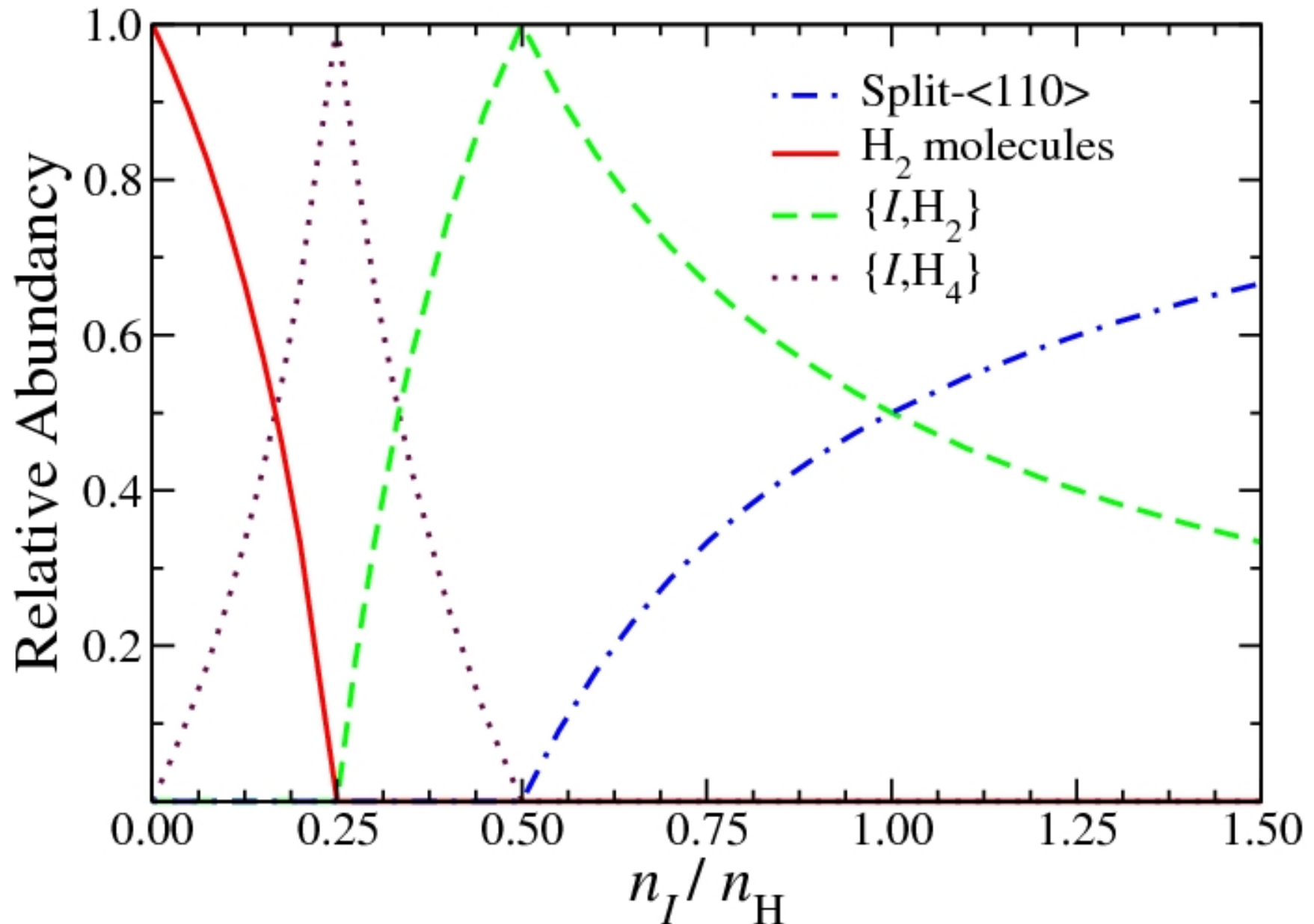


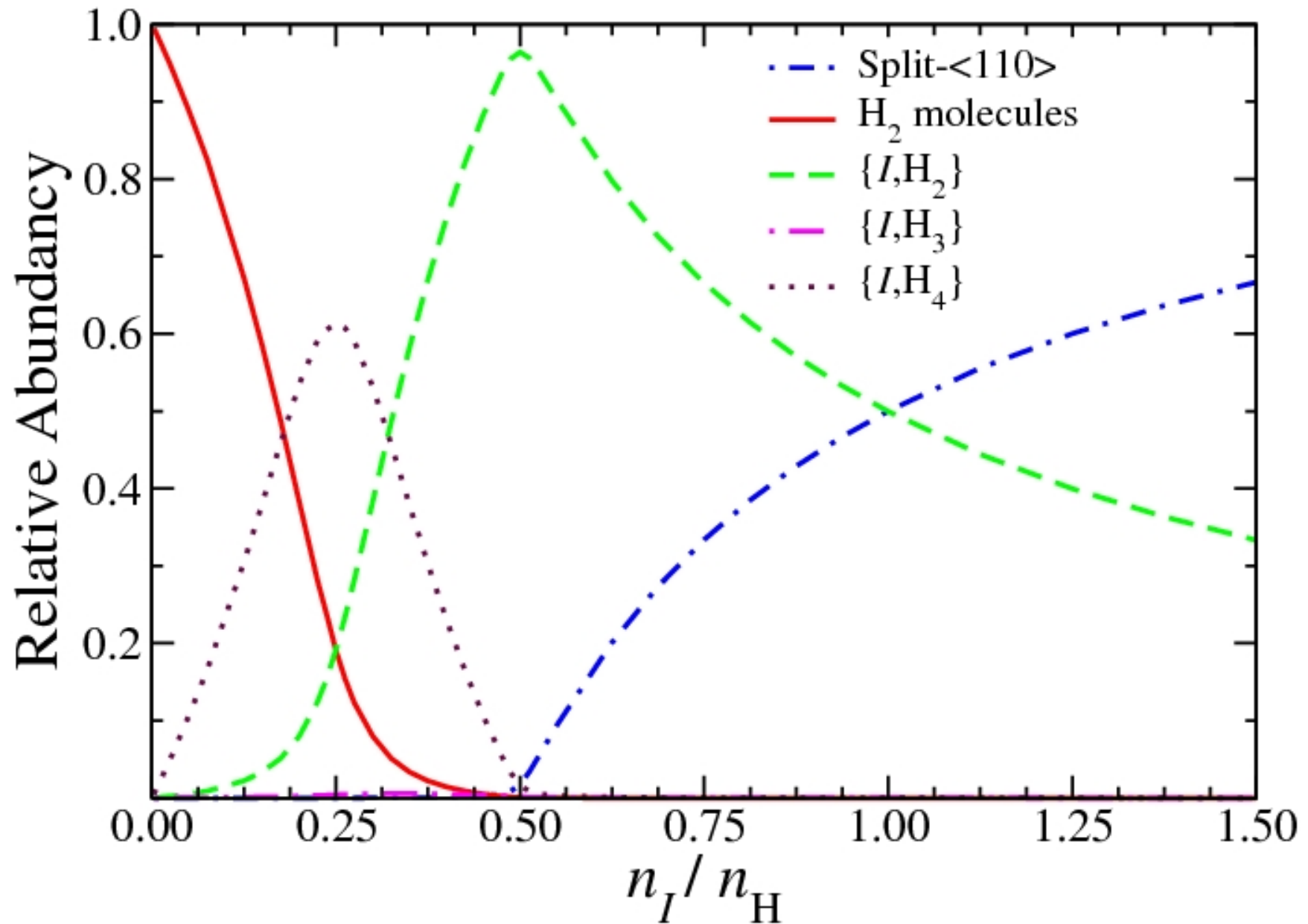






- Difficult to find the I+H₂ ground state from a 5 atom hole.
- Tried again from a 1 atom hole.
- Get the right I+H₂ defect quite quickly.
- Have also tried 1 atom holes from hexagonal site. Good results.







Random Structure Searching in Defects **works**, and can reproduce results found by other methods.

Can also find gain new **insights** into the defects that form

Get all of the metastable defects for **free**

We have a method now, that can generate results **quickly**
Fish / Polish / Embed

Constraints are important to reduce the search space.

Start with a small hole on a well-defined site and **randomise**.

The beauty of the method is in the the **simplicity** of the algorithm

Unlike other methods, we don't have to think up starting configs. that **bias** the results.



Richard Needs
Chris Pickard
Jonathan Yates
Michael Rutter

EPSRC

Engineering and Physical Sciences
Research Council

Cambridge High Performance Computing Facility